SWITCHMODE [™] **Power Rectifiers**

This series is designed for use in switching power supplies, inverters and as free wheeling diodes, these state-of-the-art devices have the following features:

Features

- Ultrafast 35 and 60 Nanosecond Recovery Times
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 Volts
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- Pb-Free Packages are Available*

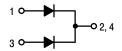
Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube



http://onsemi.com

ULTRAFAST RECTIFIERS 8.0 AMPERES 100-600 VOLTS





TO-220AB CASE 221A PLASTIC

MARKING DIAGRAM



A = Assembly Location

Y = Year W = Work Week U16 = Device Code xx = 10, 15, 20, 40, or 60 AKA = Location Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

		MUR16					
Rating	Symbol	10CT	15CT	20CT	40CT	60CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	150	200	400	600	V
Average Rectified Forward Current Per Leg Total Device, (Rated V_R), $T_C = 150$ °C Total Device	I _{F(AV)}			8.0 16			А
Peak Rectified Forward Current Per Diode Leg (Rated V _R , Square Wave, 20 kHz), T _C = 150°C	I _{FM}	16			А		
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	100			А		
Operating Junction Temperature and Storage Temperature		- 65 to +175			°C		

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Per Diode Leg)

Maximum Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	3.0	2.	.0	°C/W
ELECTRICAL CHARACTERISTICS (Per Diode Leg)					
Maximum Instantaneous Forward Voltage (Note 1) $(i_F = 8.0 \text{ Amps}, T_C = 150^{\circ}\text{C})$ $(i_F = 8.0 \text{ Amps}, T_C = 25^{\circ}\text{C})$	VF	0.895 0.975	1.00 1.30	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_C = 150^{\circ}C$) (Rated dc Voltage, $T_C = 25^{\circ}C$)	i _R	250 5.0	500 10		μΑ
Maximum Reverse Recovery Time $(I_F = 1.0 \text{ Amp, di/dt} = 50 \text{ Amps/}\mu\text{s})$ $(I_F = 0.5 \text{ Amp, }I_R = 1.0 \text{ Amp, }I_{REC} = 0.25 \text{ Amp})$	t _{rr}	35 25	60 50		ns

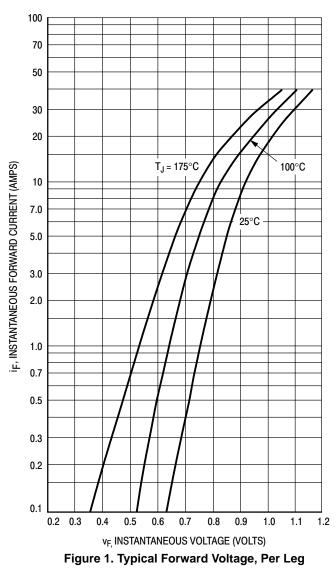
^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%

ORDERING INFORMATION

Device	Package	Shipping [†]
MUR1610CT	TO-220	50 Units / Rail
MUR1615CT	TO-220	50 Units / Rail
MUR1620CT	TO-220	50 Units / Rail
MUR1620CTG	TO-220 (Pb-Free)	50 Units / Rail
MUR1640CT	TO-220	50 Units / Rail
MUR1640CTG	TO-220 (Pb-Free)	50 Units / Rail
MUR1660CT	TO-220	50 Units / Rail
MUR1660CTG	TO-220 (Pb-Free)	50 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MUR1610CT, MUR1615CT, MUR1620CT



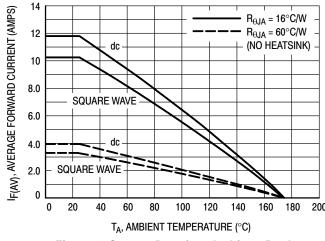


Figure 4. Current Derating, Ambient, Per Leg

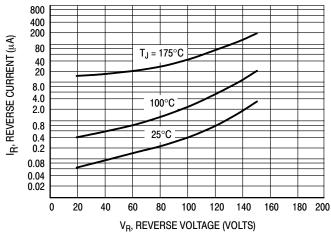


Figure 2. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

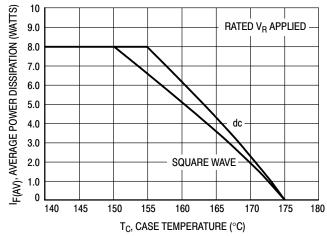


Figure 3. Current Derating, Case, Per Leg

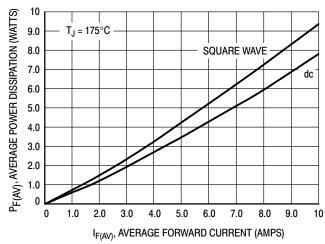
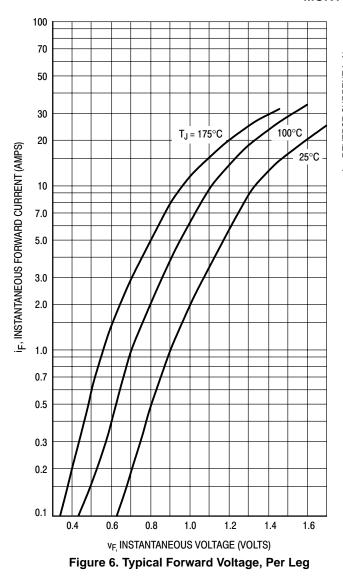


Figure 5. Power Dissipation, Per Leg

MUR1640CT



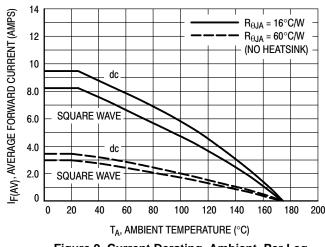


Figure 9. Current Derating, Ambient, Per Leg

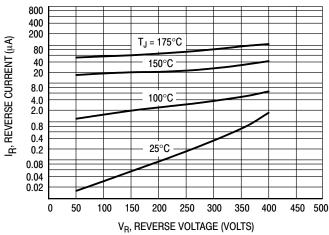


Figure 7. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these curves if V_R is sufficiently below rated V_R .

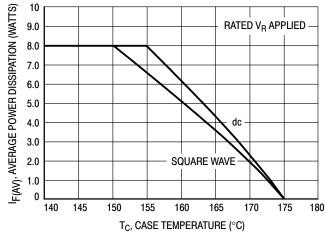


Figure 8. Current Derating, Case, Per Leg

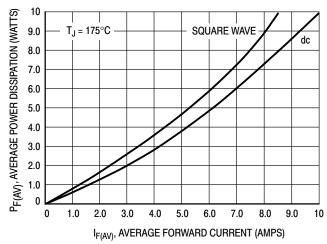
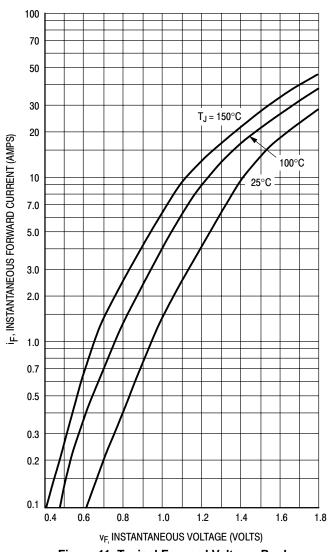
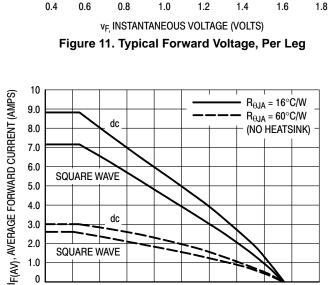


Figure 10. Power Dissipation, Per Leg

MUR1660CT





T_A, AMBIENT TEMPERATURE (°C)
Figure 14. Current Derating, Ambient, Per Leg

100

120

160

0

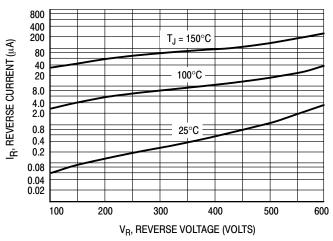


Figure 12. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

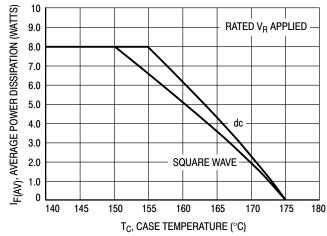


Figure 13. Current Derating, Case, Per Leg

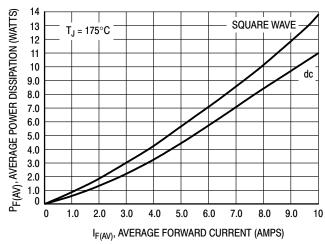


Figure 15. Power Dissipation, Per Leg

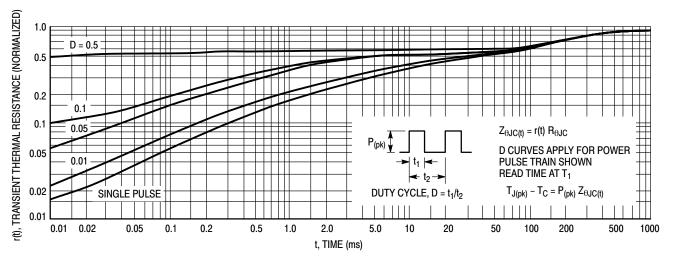


Figure 16. Thermal Response

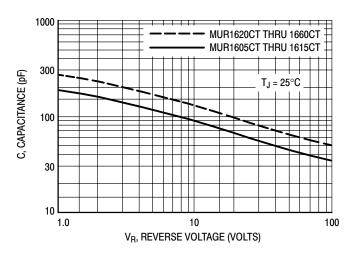
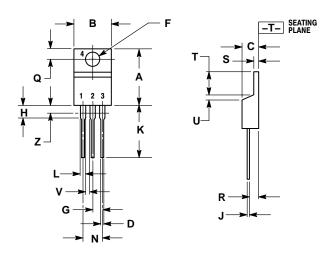


Figure 17. Typical Capacitance, Per Leg

PACKAGE DIMENSIONS

TO-220 THREE-LEAD TO-220AB

CASE 221A-09 **ISSUE AA**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
_	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

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